MA3S795D, MA3S795E (MA795WA, MA795WK)

Silicon epitaxial planar type

For switching

■ Features

- High-density mounting is possible
- Low forward voltage V_F, optimum for low voltage rectification: $V_F < 0.3 \text{ V (at } I_F = 1 \text{ mA)}$
- Optimum for high frequency rectification because of its short reverse recovery time (t_{rr})
- SS-Mini type 3-pin package

■ Absolute Maximum Ratings T_a = 25°C

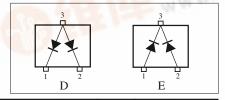
Parameter		Symbol	Rating	Unit			
Reverse voltage (DC)		V _R	30	V			
Peak reverse voltage		V _{RM}	30	V			
Peak forward current	Series	I_{FM}	150	mA			
	Double *		110				
Forward current (DC)	Series	I_F	30	mA			
	Double *		20				
Junction temperature		T _j	125	°C			
Storage temperature		T_{stg}	-55 to +125	°C			
Note) *: Value per cl	nip	100	-7.75	WIT			
■ Electrical Characteristics T _a = 25°C							

Unit: mm $0.12^{+0.05}_{-0.02}$ (0.51)(0.80) (0.80) $1.60^{+0.05}_{-0.03}$ MA3S795D MA3S795E Cathode 1 Anode 1 EIAJ: SC-89 2 Cathode 2 Anode 2 SSMini3-F2 Package Anode 1, 2 Cathode 1, 2

Marking Symbol

MA3S795D: M3D
 MA3S795E: M3D

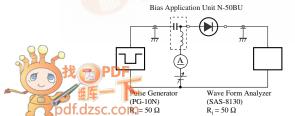
Internal Connection

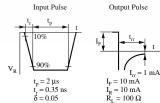


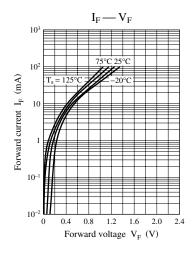
■ Electrical Characteristics $T_a = 25$ °C

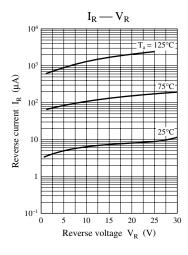
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse current (DC)	I_R	$V_R = 30 \text{ V}$			30	μΑ
Forward voltage (DC)	V _{F1}	$I_F = 1 \text{ mA}$			0.3	V
	V _{F2}	$I_F = 30 \text{ mA}$			1	
Terminal capacitance	C _t	$V_R = 1 \text{ V, } f = 1 \text{ MHz}$		1.5	- 4	pF
Reverse recovery time *	t _{rr}	$I_F = I_R = 10 \text{ mA}$ $I_{rr} = 1 \text{ mA}, R_L = 100 \Omega$		1		ns
Detection efficiency	η	$V_{in} = 3 V_{(peak)}, f = 30 MHz$ $R_L = 3.9 k\Omega, C_L = 10 pF$		65		%

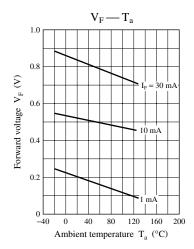
- Note) 1. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
 - 2. Rated input/output frequency: 2 GHz
- 3. *: t_{rr} measuring instrument

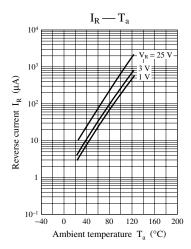


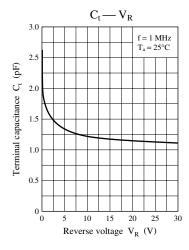












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